



HIGH SPEED CMOS TIMER

GENERAL DESCRIPTION

The ALD555 timer is a high performance monolithic timing circuit built with advanced silicon gate CMOS technology. It offers the benefits of high input impedance, thereby allowing smaller timing capacitors and longer timing cycle; high speed, with typical cycle time of 500ns; low power dissipation for battery operated environment; reduced supply current spikes, allowing smaller and lower cost decoupling capacitors. It is capable of producing accurate time delays and oscillations in both monostable and astable operation. It operates in the one-shot (monostable) mode or 50% duty cycle free running oscillation mode with a single resistor and one capacitor. The inputs and outputs are fully compatible with CMOS, NMOS or TTL logic.

There are three matched internal resistors (approximately 200KΩ each) that set the threshold and trigger levels at two-thirds and one-third respectively of V+. These levels can be adjusted by using the control terminal (pin 5). When the trigger input is below the trigger level, the output is in the high state and sourcing 2mA. When threshold input is above the threshold level at the same time the trigger input is above the trigger level, the internal flip-flop is reset, the output goes to the low state and sinks up to 10mA. The reset input overrides all other inputs and when it is active (reset voltage less than 1V), the output is in the low state.

FEATURES

- Functional equivalent to NE555 with greatly expanded high and low frequency ranges
- High speed, low power, monolithic CMOS technology
- Low supply current: 100μA typical
- Extremely low trigger, threshold and reset currents: 1pA typical
- High speed operation -- 2MHz oscillation
- Low operating supply voltage of 2 to 12V
- Operates in both monostable and astable modes
- Fixed 50% duty cycle or adjustable duty cycle
- CMOS, NMOS and TTL compatible input/output
- High discharge sinking current of 80mA
- Low supply current spikes

ORDERING INFORMATION ("L" suffix denotes lead-free (RoHS))

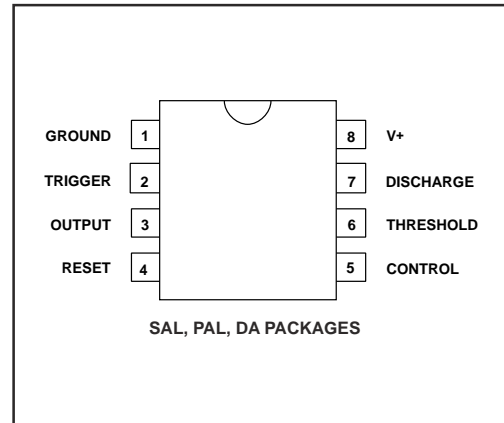
Operating Temperature Range *		
0°C to +70°C	0°C to +70°C	-55°C to +125°C
8-Pin Small Outline Package (SOIC)	8-Pin Plastic DIP Package	8-Pin CERDIP Package
ALD555SAL	ALD555PAL	ALD555DA

* Contact factory for leaded (non-RoHS) or high temperature versions.

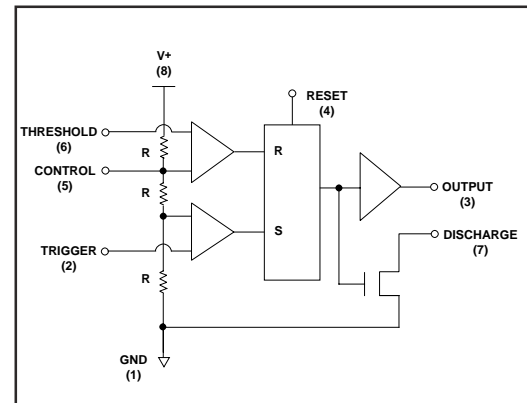
APPLICATIONS

- High speed one-shot (monostable) pulse generation
- Precision timing
- Sequential timing
- Long delay timer
- Pulse width and pulse position modulation
- Missing pulse detector
- Frequency divider

PIN CONFIGURATION



BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Supply voltage, V+ _____ 13.2V
 Input voltage range _____ -0.3V to V+ +0.3V
 Power dissipation _____ 600 mW
 Operating temperature range SAL, PAL packages _____ 0°C to + 70°C
 DA package _____ -55°C to +125°C
 Storage temperature range _____ -65°C to +150°C
 Lead temperature, 10 seconds _____ +260°C

OPERATING ELECTRICAL CHARACTERISTICS T_A = 25°C V+ = +5V unless otherwise specified

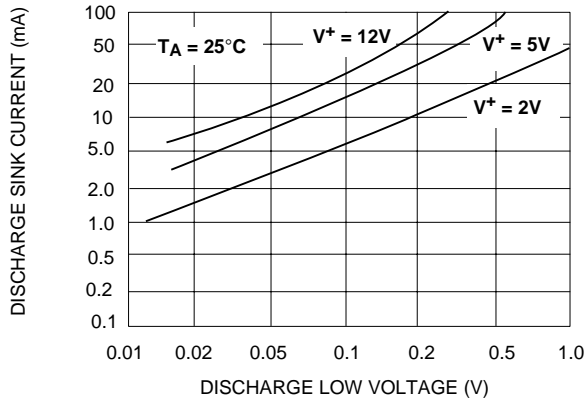
Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Supply Voltage	V+	2		12	V	
Supply Current	I _S		100	180	μA	Outputs Unloaded
Timing error / Astable mode Initial Accuracy	t _{err}		1.0	2.2	%	C = 0.1μF
Drift with Temperature ¹ Drift with Supply Voltage ¹	Δt/ΔT Δt/ΔV+		10.0 0.1		ppm/°C %/V	R _A = 1KΩ R _B = 1KΩ
Threshold Voltage	V _{TH}	3.233	3.333	3.433	V	
Trigger Voltage	V _{TRIG}	1.607	1.667	1.737	V	
Trigger Current ²	I _{TRIG}		.001	0.2	nA	
Reset Voltage	V _{RST}	0.4	0.7	1.0	V	
Reset Current ²	I _{RST}		.001	0.2	nA	
Threshold Current ²	I _{TH}		.001	0.2	nA	
Control Voltage Level	V _{CONT}	3.273	3.333	3.393	V	
Output Voltage Drop (Low)	V _{OL}		0.2	0.4	V	I _{SINK} = 10mA
Output Voltage Drop (High)	V _{OH}			4.2	V	I _{SOURCE} = -2mA
Rise Time of Output ¹	t _r		15	30	ns	R _L = 10MΩ
Fall Time of Output ¹	t _f		10	30	ns	C _L = 10pF
Discharge Transistor Leakage Current	I _{DL}		.01		nA	
Discharge Voltage Drop	V _{DISC}		0.5 0.2	1.0 0.4	V V	I _{DISCHARGE} = 80mA I _{DISCHARGE} = 30mA
Maximum Frequency Astable Mode	f _{MAX}	1.4	2		MHz	R _A = 470Ω R _B = 200Ω C _T = 200pF

Notes: ¹ Sample tested parameters.

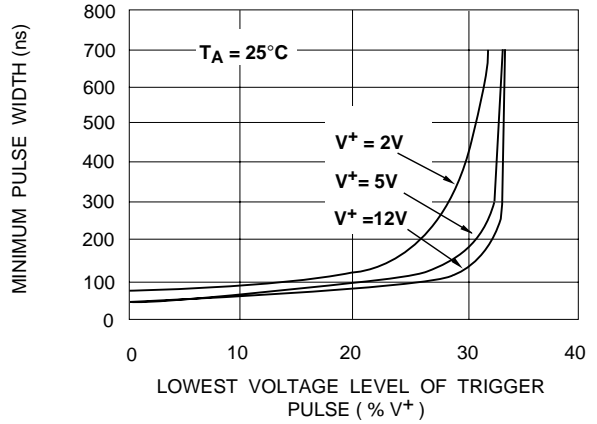
² Consists of junction leakage currents with strong temperature dependence.

TYPICAL PERFORMANCE CHARACTERISTICS

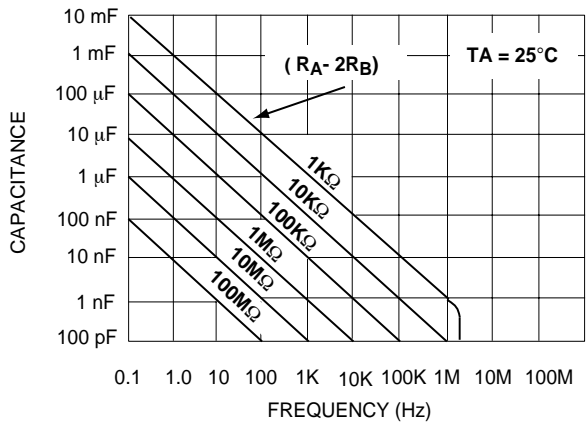
DISCHARGE OUTPUT SINK CURRENT AS A FUNCTION OF DISCHARGE LOW VOLTAGE



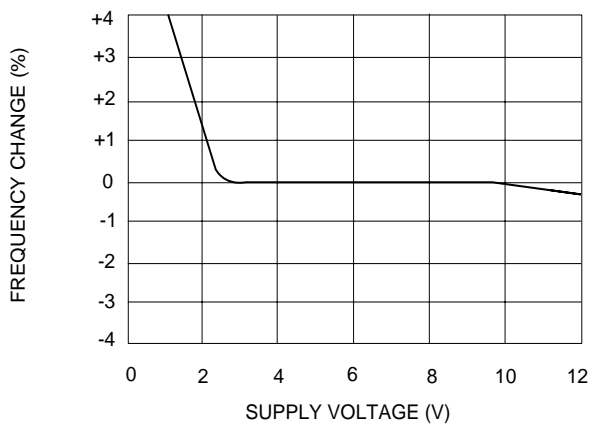
MINIMUM PULSE WIDTH REQUIRED FOR TRIGGERING



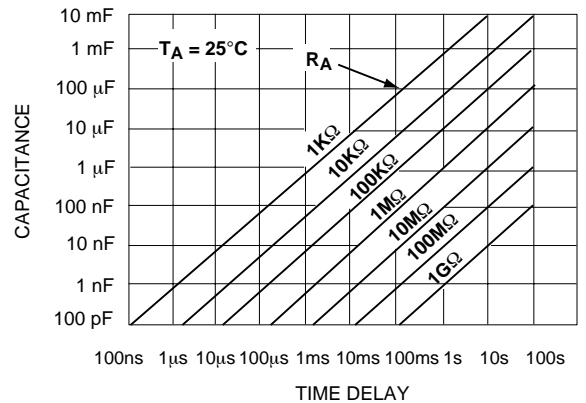
FREE RUNNING FREQUENCY AS A FUNCTION OF R_A , R_B AND C



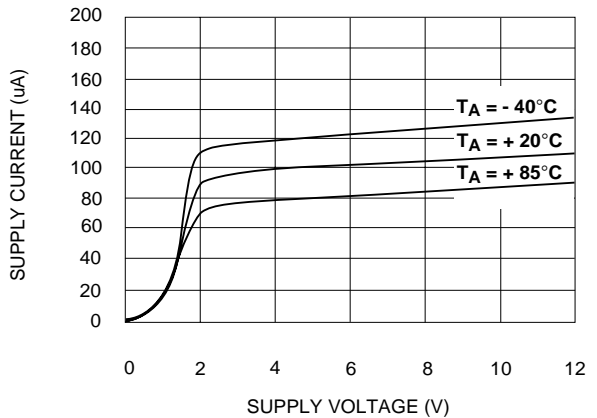
FREQUENCY CHANGE IN THE ASTABLE MODE AS A FUNCTION OF SUPPLY VOLTAGE



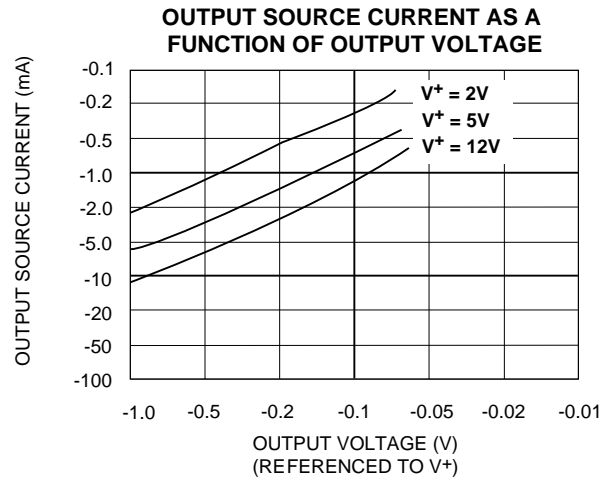
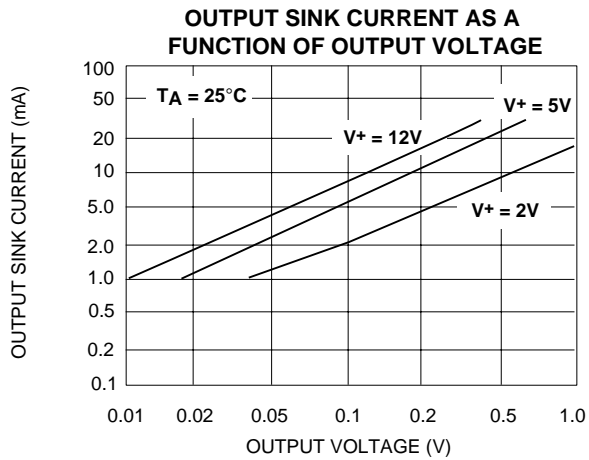
TIME DELAY IN THE MONOSTABLE MODE AS A FUNCTION OF R_A AND C



SUPPLY CURRENT AS A FUNCTION OF SUPPLY VOLTAGE

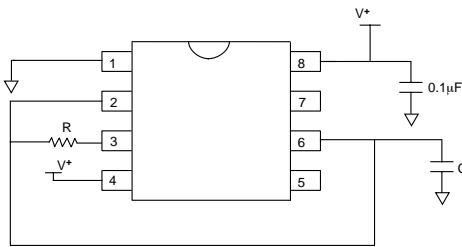


TYPICAL PERFORMANCE CHARACTERISTICS (cont'd)



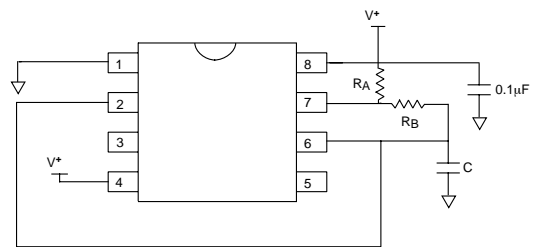
TYPICAL APPLICATIONS

ASTABLE MODE OPERATION 50% DUTY CYCLE



$$\text{Frequency } f = 1 / (1.4 R C)$$

ASTABLE MODE OPERATION (FREE RUNNING OSCILLATOR)

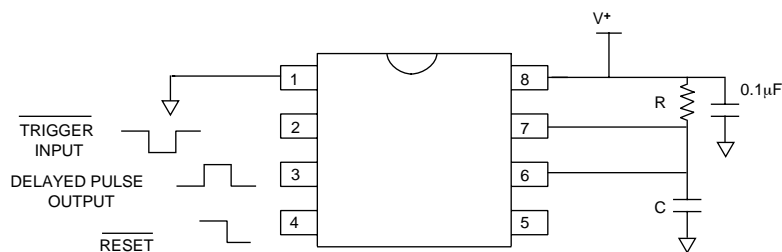


$$\text{Frequency } f = 1.46 / (R_A + 2R_B)C$$

$$\text{Duty Cycle DC} = R_B / (R_A + 2R_B)$$

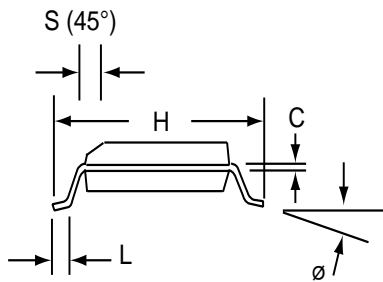
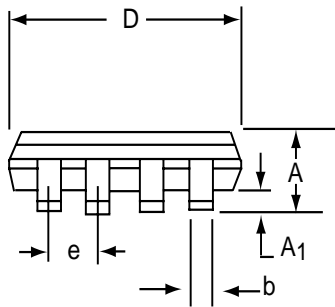
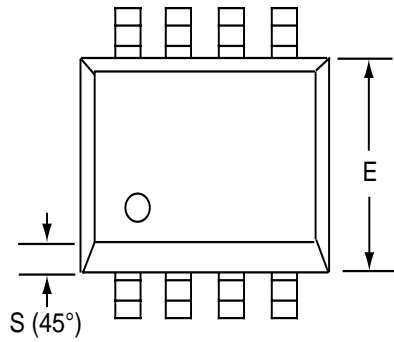
MONOSTABLE MODE OPERATION (ONE SHOT PULSE)

Pulse Delay $t_d = 1.1 R C$



SOIC-8 PACKAGE DRAWING

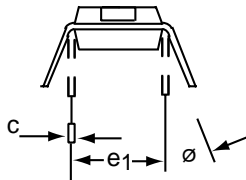
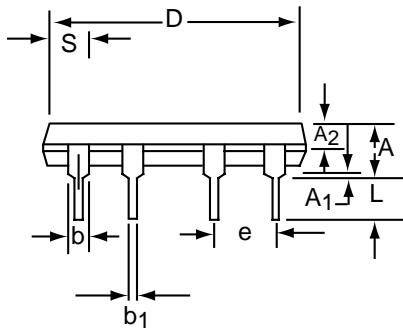
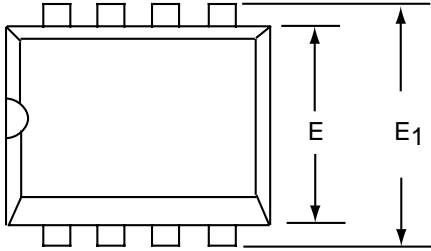
8 Pin Plastic SOIC Package



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.25	0.004	0.010
b	0.35	0.45	0.014	0.018
C	0.18	0.25	0.007	0.010
D-8	4.69	5.00	0.185	0.196
E	3.50	4.05	0.140	0.160
e	1.27 BSC		0.050 BSC	
H	5.70	6.30	0.224	0.248
L	0.60	0.937	0.024	0.037
ø	0°	8°	0°	8°
S	0.25	0.50	0.010	0.020

PDIP-8 PACKAGE DRAWING

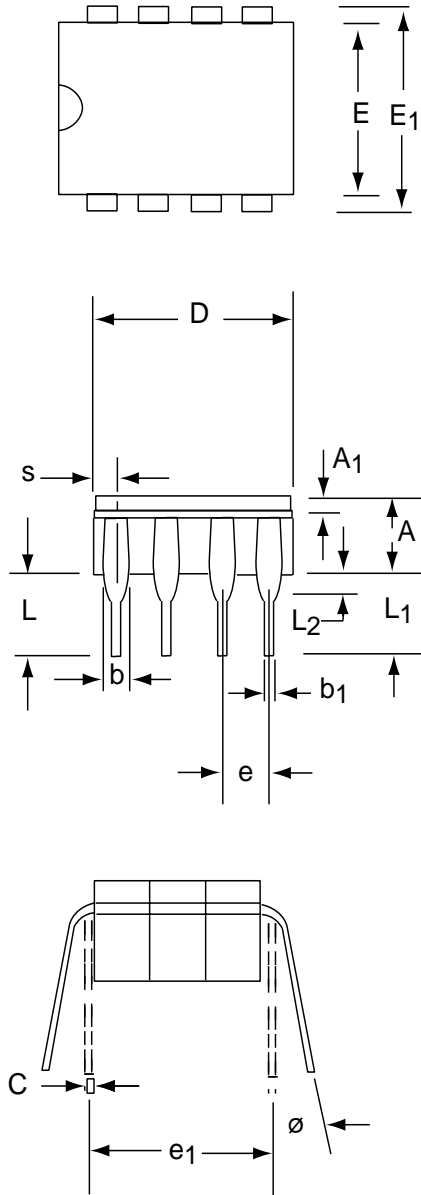
8 Pin Plastic DIP Package



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	3.81	5.08	0.105	0.200
A ₁	0.38	1.27	0.015	0.050
A ₂	1.27	2.03	0.050	0.080
b	0.89	1.65	0.035	0.065
b ₁	0.38	0.51	0.015	0.020
c	0.20	0.30	0.008	0.012
D-8	9.40	11.68	0.370	0.460
E	5.59	7.11	0.220	0.280
E ₁	7.62	8.26	0.300	0.325
e	2.29	2.79	0.090	0.110
e ₁	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
S-8	1.02	2.03	0.040	0.080
φ	0°	15°	0°	15°

CERDIP-8 PACKAGE DRAWING

8 Pin CERDIP Package



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	3.55	5.08	0.140	0.200
A₁	1.27	2.16	0.050	0.085
b	0.97	1.65	0.038	0.065
b₁	0.36	0.58	0.014	0.023
C	0.20	0.38	0.008	0.015
D-8	--	10.29	--	0.405
E	5.59	7.87	0.220	0.310
E₁	7.73	8.26	0.290	0.325
e	2.54 BSC		0.100 BSC	
e₁	7.62 BSC		0.300 BSC	
L	3.81	5.08	0.150	0.200
L₁	3.18	--	0.125	--
L₂	0.38	1.78	0.015	0.070
S	--	2.49	--	0.098
∅	0°	15°	0°	15°



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Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
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- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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